New Jersey Semi-Conductor Products, Inc.

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## 1N38

## **GOLD BONDED GERMANIUM DIODE**

### **FEATURES**

Low forward voltage drop—low power consumption Thirty years of proven reliability—one million hours mean time between failures (MTBF) Very low noise level Metallurgically bonded

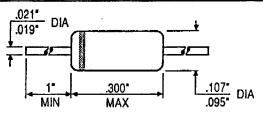
## ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage Peak Forward Current Operating Temperature Range Average Power Dissipation 100 Volts 500 mA - 65 °C to 85 °C 80 mW

### **ELECTRICAL CHARACTERISTICS**

	Symbol	Conditions	Min	Max	Unit	T℃	1
Peak Inverse Voltage	PIV	1 mA	100		v	25 °C	
Reverse Current	Ir	10 V		25	μΑ	25 °C	
Forward Voltage	Vf	7.5 mA		1	V	25 °C	l
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#### MECHANICAL





NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

# **Quality Semi-Conductors**